



# 4-Mbit (512K x 8) Static RAM

## Part Number: DPA71049DV3302A

The DPA71049DV3302A is a high performance CMOS Static RAM organized as 512K words by 8-bits. Easy memory expansion is provided by an Active LOW Chip Enable ( $\overline{CE}$ ), an Active LOW Output Enable ( $\overline{OE}$ ), and tri-state drivers.

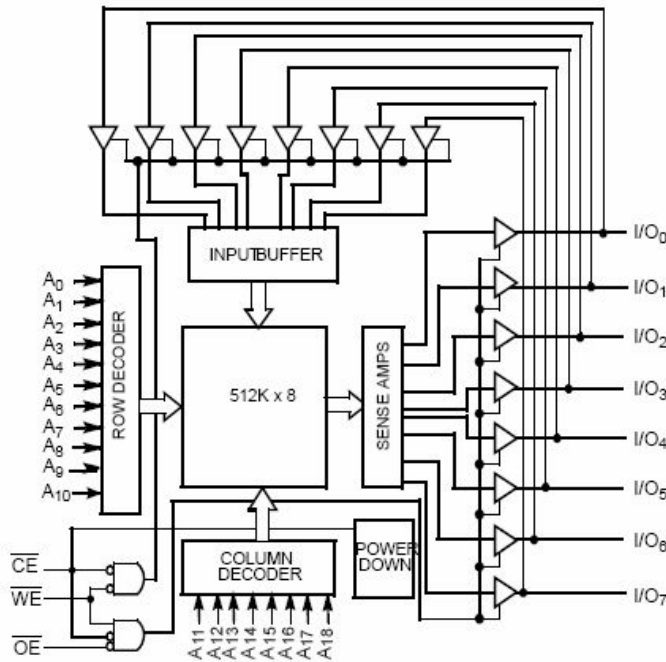
Writing to the device is accomplished by enabling the Chip ( $\overline{CE}$ ) and Write Enable ( $\overline{WE}$ ) inputs LOW. Data on the eight IO pins ( $IO_0$  through  $IO_7$ ) is then written into the location specified on the address pins ( $A_0$  through  $A_{18}$ ).

Reading from the device can be accomplished by enabling the Chip ( $\overline{CE}$ ) and Output Enable ( $\overline{OE}$ ) LOW while forcing Write Enable ( $\overline{WE}$ ) HIGH. Under these conditions, the contents of the memory location specified by the address pins appear on the IO pins.

The eight input/output pins ( $IO_0$  through  $IO_7$ ) are placed in a high-impedance state when the device is deselected ( $\overline{CE}$  HIGH), the outputs are disabled ( $\overline{OE}$

- -55° to +125°C operating temperature
- High speed
  - $t_{AA} = 12 \text{ ns}$
- Low active power
  - $I_{CC} = 95 \text{ mA @ } 12 \text{ ns}$
- Low CMOS standby power
  - $I_{SB2} = 15 \text{ mA}$
- 2.0V data retention
- Supply voltage
  - 3.3 V dc
- Automatic power down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with  $\overline{CE}$  and  $\overline{OE}$  features
- 44-pin SO ceramic flatpack, same footprint as 44-pin TSOP II
- Custom packaging is available
- This product uses Cypress CYC71049DV33 die and is tested to meet military and space operational environment requirements.

### Logic Block Diagram



### Pin Configuration

